

LM4250

Programmable Operational Amplifier

General Description

The LM4250 and LM4250C are extremely versatile programmable monolithic operational amplifiers. A single external master bias current setting resistor programs the input bias current, input offset current, quiescent power consumption, slew rate, input noise, and the gain-bandwidth product. The device is a truly general purpose operational amplifier.

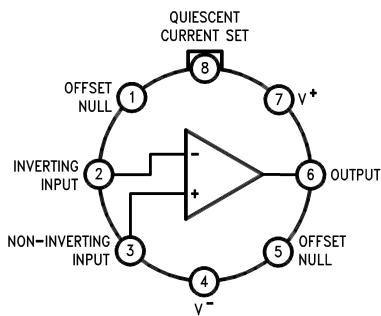
The LM4250C is identical to the LM4250 except that the LM4250C has its performance guaranteed over a 0°C to +70°C temperature range instead of the -55°C to +125°C temperature range of the LM4250.

Features

- ±1V to ±18V power supply operation
- 3 nA input offset current
- Standby power consumption as low as 500 nW
- No frequency compensation required
- Programmable electrical characteristics
- Offset voltage nulling capability
- Can be powered by two flashlight batteries
- Short circuit protection

Connection Diagrams

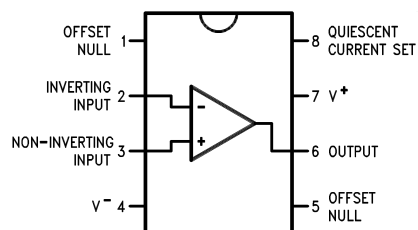
Metal Can Package



Top View

DS009300-2

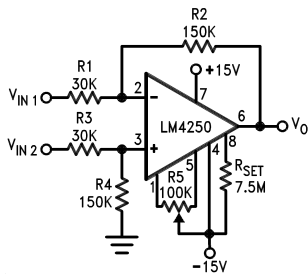
Dual-In-Line Package



Top View

DS009300-5

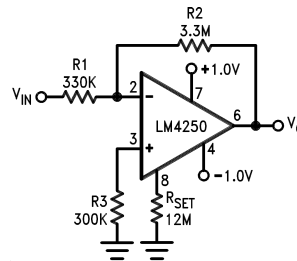
X5 Difference Amplifier



DS009300-3

Quiescent $P_D = 0.6 \text{ mW}$

500 Nano-Watt X10 Amplifier



DS009300-4

Quiescent $P_D = 500 \text{ nW}$

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

(Note 3)

| | LM4250 | LM4250C |
|----------------------------------------------|---------------------------------|------------------------------|
| Supply Voltage | ±18V | ±18V |
| Operating Temp. Range | -55°C ≤ T _A ≤ +125°C | 0°C ≤ T _A ≤ +70°C |
| Differential Input Voltage | ±30V | ±30V |
| Input Voltage (Note 2) | ±15V | ±15V |
| I _{SET} Current | 150 nA | 150 nA |
| Output Short Circuit Duration | Continuous | Continuous |
| T _{JMAX} | | |
| H-Package | 150°C | 100°C |
| N-Package | | 100°C |
| J-Package | 150°C | 100°C |
| M-Package | | 100°C |
| Power Dissipation at T _A = 25°C | | |
| H-Package (Still Air) | 500 mW | 300 mW |
| (400 LF/Min Air Flow) | 1200 mW | 1200 mW |
| N-Package | | 500 mW |
| J-Package | 1000 mW | 600 mW |
| M-Package | | 350 mW |
| Thermal Resistance (Typical) θ _{JA} | | |
| H-Package (Still Air) | 165°C/W | 165°C/W |
| (400 LF/Min Air Flow) | 65°C/W | 65°C/W |
| N-Package | | 130°C/W |
| J-Package | 108°C/W | 108°C/W |
| M-Package | | 190°C/W |
| (Typical) θ _{JC} | | |
| H-Package | 21°C/W | 21°C/W |
| Storage Temperature Range | -65°C to +150°C | -65°C to +150°C |
| Soldering Information | | |
| Dual-In-Line Package | | |
| Soldering (10 seconds) | 260°C | |
| Small Outline Package | | |
| Vapor Phase (60 seconds) | 215°C | |
| Infrared (15 seconds) | 220°C | |

See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.

ESD tolerance (Note 4) 800V

Note 1: "Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits.

Note 2: For supply voltages less than ±15V, the absolute maximum input voltage is equal to the supply voltage.

Note 3: Refer to RETS4250X for military specifications.

Note 4: Human body model, 1.5 kΩ in series with 100 pF.

Resistor Biasing

Set Current Setting Resistor to V^-

| V_S | I_{SET} | | | | |
|-------------|-----------------|-----------------|-----------------|-----------------|-----------------|
| | 0.1 μA | 0.5 μA | 1.0 μA | 5 μA | 10 μA |
| $\pm 1.5V$ | 25.6 M Ω | 5.04 M Ω | 2.5 M Ω | 492 k Ω | 244 k Ω |
| $\pm 3.0V$ | 55.6 M Ω | 11.0 M Ω | 5.5 M Ω | 1.09 M Ω | 544 k Ω |
| $\pm 6.0V$ | 116 M Ω | 23.0 M Ω | 11.5 M Ω | 2.29 M Ω | 1.14 M Ω |
| $\pm 9.0V$ | 176 M Ω | 35.0 M Ω | 17.5 M Ω | 3.49 M Ω | 1.74 M Ω |
| $\pm 12.0V$ | 236 M Ω | 47.0 M Ω | 23.5 M Ω | 4.69 M Ω | 2.34 M Ω |
| $\pm 15.0V$ | 296 M Ω | 59.0 M Ω | 29.5 M Ω | 5.89 M Ω | 2.94 M Ω |

Electrical Characteristics

LM4250 ($-55^\circ C \leq T_A \leq +125^\circ C$ unless otherwise specified.) $T_A = T_J$

| Parameter | Conditions | $V_S = \pm 1.5V$ | | | |
|--------------------------------|-----------------------------------------------------------------------------------|---------------------|--------------|----------------------|----------------|
| | | $I_{SET} = 1 \mu A$ | | $I_{SET} = 10 \mu A$ | |
| | | Min | Max | Min | Max |
| V_{OS} | $R_S \leq 100 k\Omega$, $T_A = 25^\circ C$ | | 3 mV | | 5 mV |
| I_{OS} | $T_A = 25^\circ C$ | | 3 nA | | 10 nA |
| I_{bias} | $T_A = 25^\circ C$ | | 7.5 nA | | 50 nA |
| Large Signal Voltage Gain | $R_L = 100 k\Omega$, $T_A = 25^\circ C$ $V_O = \pm 0.6V$, $R_L = 10 k\Omega$ | 40k | | 50k | |
| Supply Current | $T_A = 25^\circ C$ | | 7.5 μA | | 80 μA |
| Power Consumption | $T_A = 25^\circ C$ | | 23 μW | | 240 μW |
| V_{OS} | $R_S \leq 100 k\Omega$ | | 4 mV | | 6 mV |
| I_{OS} | $T_A = +125^\circ C$ $T_A = -55^\circ C$ | | 5 nA 3 nA | | 10 nA 10 nA |
| I_{bias} | | | 7.5 nA | | 50 nA |
| Input Voltage Range | | $\pm 0.6V$ | | $\pm 0.6V$ | |
| Large Signal Voltage Gain | $V_O = \pm 0.5V$, $R_L = 100 k\Omega$ $R_L = 10 k\Omega$ | 30k | | 30k | |
| Output Voltage Swing | $R_L = 100 k\Omega$ $R_L = 10 k\Omega$ | $\pm 0.6V$ | | $\pm 0.6V$ | |
| Common Mode Rejection Ratio | $R_S \leq 10 k\Omega$ | 70 dB | | 70 dB | |
| Supply Voltage Rejection Ratio | $R_S \leq 10 k\Omega$ | 76 dB | | 76 dB | |
| Supply Current | | | 8 μA | | 90 μA |

| Parameter | Conditions | $V_S = \pm 15V$ | | | |
|---------------------------|----------------------------------------------------------------------------------|---------------------|---------------|----------------------|----------------|
| | | $I_{SET} = 1 \mu A$ | | $I_{SET} = 10 \mu A$ | |
| | | Min | Max | Min | Max |
| V_{OS} | $R_S \leq 100 k\Omega$, $T_A = 25^\circ C$ | | 3 mV | | 5 mV |
| I_{OS} | $T_A = 25^\circ C$ | | 3 nA | | 10 nA |
| I_{bias} | $T_A = 25^\circ C$ | | 7.5 nA | | 50 nA |
| Large Signal Voltage Gain | $R_L = 100 k\Omega$, $T_A = 25^\circ C$ $V_O = \pm 10V$, $R_L = 10 k\Omega$ | 100k | | 100k | |
| Supply Current | $T_A = 25^\circ C$ | | 10 μA | | 90 μA |
| Power Consumption | $T_A = 25^\circ C$ | | 300 μW | | 2.7 mW |
| V_{OS} | $R_S \leq 100 k\Omega$ | | 4 mV | | 6 mV |
| I_{OS} | $T_A = +125^\circ C$ $T_A = -55^\circ C$ | | 25 nA 3 nA | | 25 nA 10 nA |
| I_{bias} | | | 7.5 nA | | 50 nA |
| Input Voltage Range | | $\pm 13.5V$ | | $\pm 13.5V$ | |

Electrical Characteristics (Continued)

| Parameter | Conditions | $V_S = \pm 15V$ | | | |
|--------------------------------|----------------------------------------------------------|---------------------|-------------|----------------------|-------------|
| | | $I_{SET} = 1 \mu A$ | | $I_{SET} = 10 \mu A$ | |
| | | Min | Max | Min | Max |
| Large Signal Voltage Gain | $V_O = \pm 10V, R_L = 100 k\Omega$ $R_L = 10 k\Omega$ | 50k | | 50k | |
| Output Voltage Swing | $R_L = 100 k\Omega$ $R_L = 10 k\Omega$ | $\pm 12V$ | | $\pm 12V$ | |
| Common Mode Rejection Ratio | $R_S \leq 10 k\Omega$ | 70 dB | | 70 dB | |
| Supply Voltage Rejection Ratio | $R_S \leq 10 k\Omega$ | 76 dB | | 76 dB | |
| Supply Current | | | 11 μA | | 100 μA |
| Power Consumption | | | 330 μW | | 3 mW |

Electrical Characteristics

LM4250C ($0^\circ C \leq T_A \leq +70^\circ C$ unless otherwise specified.) $T_A = T_J$

| Parameter | Conditions | $V_S = \pm 1.5V$ | | | |
|--------------------------------|-----------------------------------------------------------------------------|---------------------|------------|----------------------|-------------|
| | | $I_{SET} = 1 \mu A$ | | $I_{SET} = 10 \mu A$ | |
| | | Min | Max | Min | Max |
| V_{OS} | $R_S \leq 100 k\Omega, T_A = 25^\circ C$ | | 5 mV | | 6 mV |
| I_{OS} | $T_A = 25^\circ C$ | | 6 nA | | 20 nA |
| I_{bias} | $T_A = 25^\circ C$ | | 10 nA | | 75 nA |
| Large Signal Voltage Gain | $R_L = 100 k\Omega, T_A = 25^\circ C$ $V_O = \pm 0.6V, R_L = 10 k\Omega$ | 25k | | 25k | |
| Supply Current | $T_A = 25^\circ C$ | | 8 μA | | 90 μA |
| Power Consumption | $T_A = 25^\circ C$ | | 24 μW | | 270 μW |
| V_{OS} | $R_S \leq 10 k\Omega$ | | 6.5 mV | | 7.5 mV |
| I_{OS} | | | 8 nA | | 25 nA |
| I_{bias} | | | 10 nA | | 80 nA |
| Input Voltage Range | | $\pm 0.6V$ | | $\pm 0.6V$ | |
| Large Signal Voltage Gain | $V_O = \pm 0.5V, R_L = 100 k\Omega$ $R_L = 10 k\Omega$ | 25k | | 25k | |
| Output Voltage Swing | $R_L = 100 k\Omega$ $R_L = 10 k\Omega$ | $\pm 0.6V$ | | $\pm 0.6V$ | |
| Common Mode Rejection Ratio | $R_S \leq 10 k\Omega$ | 70 dB | | 70 dB | |
| Supply Voltage Rejection Ratio | $R_S \leq 10 k\Omega$ | 74 dB | | 74 dB | |
| Supply Current | | | 8 μA | | 90 μA |
| Power Consumption | | | 24 μW | | 270 μW |

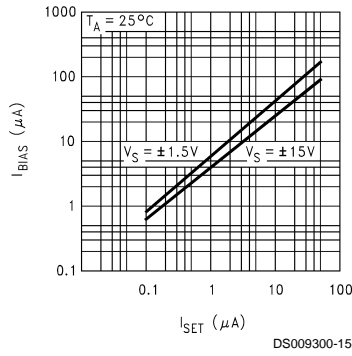
| Parameter | Conditions | $V_S = \pm 15V$ | | | |
|---------------------------|----------------------------------------------------------------------------|---------------------|-------------|----------------------|-------------|
| | | $I_{SET} = 1 \mu A$ | | $I_{SET} = 10 \mu A$ | |
| | | Min | Max | Min | Max |
| V_{OS} | $R_S \leq 100 k\Omega, T_A = 25^\circ C$ | | 5 mV | | 6 mV |
| I_{OS} | $T_A = 25^\circ C$ | | 6 nA | | 20 nA |
| I_{bias} | $T_A = 25^\circ C$ | | 10 nA | | 75 nA |
| Large Signal Voltage Gain | $R_L = 100 k\Omega, T_A = 25^\circ C$ $V_O = \pm 10V, R_L = 10 k\Omega$ | 60k | | 60k | |
| Supply Current | $T_A = 25^\circ C$ | | 11 μA | | 100 μA |
| Power Consumption | $T_A = 25^\circ C$ | | 330 μW | | 3 mW |
| V_{OS} | $R_S \leq 100 k\Omega$ | | 6.5 mV | | 7.5 mV |
| I_{OS} | | | 8 nA | | 25 nA |
| I_{bias} | | | 10 nA | | 80 nA |

Electrical Characteristics (Continued)

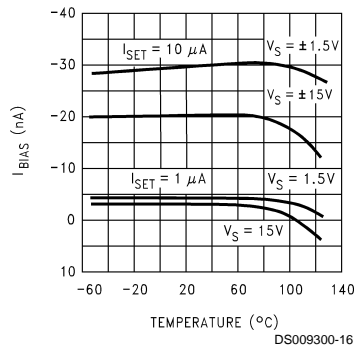
| Parameter | Conditions | $V_S = \pm 15V$ | | | |
|--------------------------------|----------------------------------------------------------|---------------------|-----|----------------------|-----|
| | | $I_{SET} = 1 \mu A$ | | $I_{SET} = 10 \mu A$ | |
| | | Min | Max | Min | Max |
| Input Voltage Range | | $\pm 13.5V$ | | $\pm 13.5V$ | |
| Large Signal Voltage Gain | $V_O = \pm 10V, R_L = 100 k\Omega$ $R_L = 10 k\Omega$ | 50k | | 50k | |
| Output Voltage Swing | $R_L = 100 k\Omega$ $R_L = 10 k\Omega$ | $\pm 12V$ | | $\pm 12V$ | |
| Common Mode Rejection Ratio | $R_S \leq 10 k\Omega$ | 70 dB | | 70 dB | |
| Supply Voltage Rejection Ratio | $R_S \leq 10 k\Omega$ | 74 dB | | 74 dB | |
| Supply Current | | 11 μA | | 100 μA | |
| Power Consumption | | 330 μW | | 3 mW | |

Typical Performance Characteristics

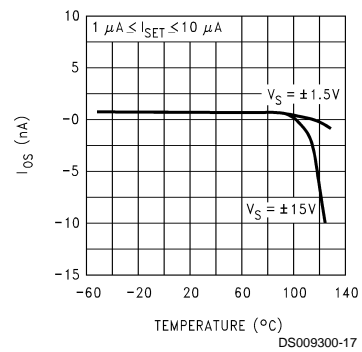
Input Bias Current vs I_{SET}



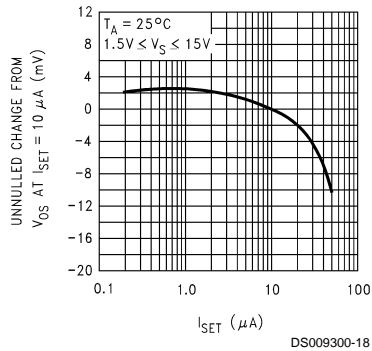
Input Bias Current vs Temperature



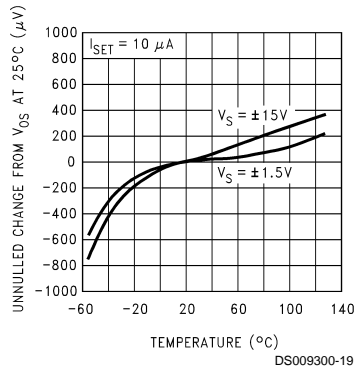
Input Offset Current vs Temperature



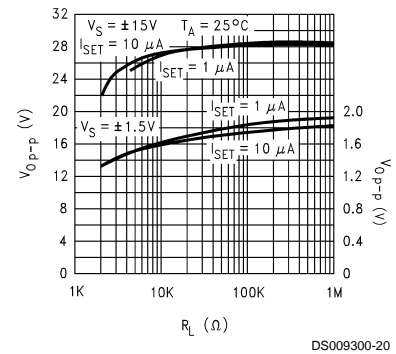
Unnull'd Input Offset Voltage Change vs I_{SET}



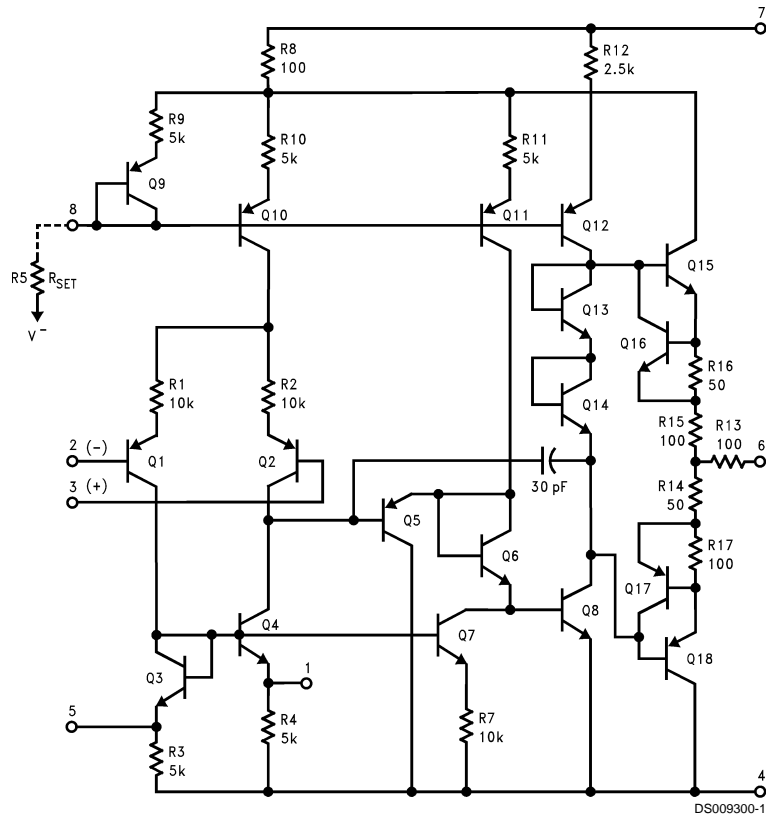
Unnull'd Input Offset Voltage Change vs Temperature



Peak to Peak Output Voltage Swing vs Load Resistance



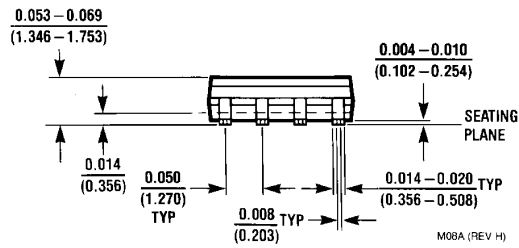
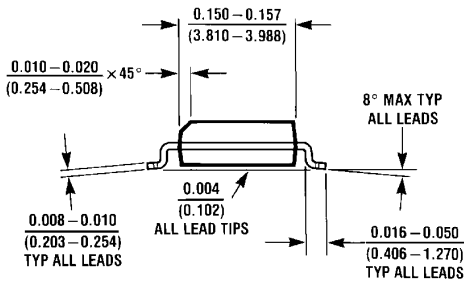
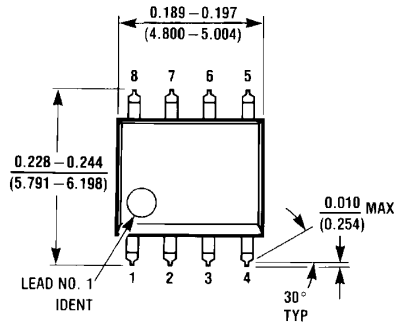
Schematic Diagram



Ordering Information

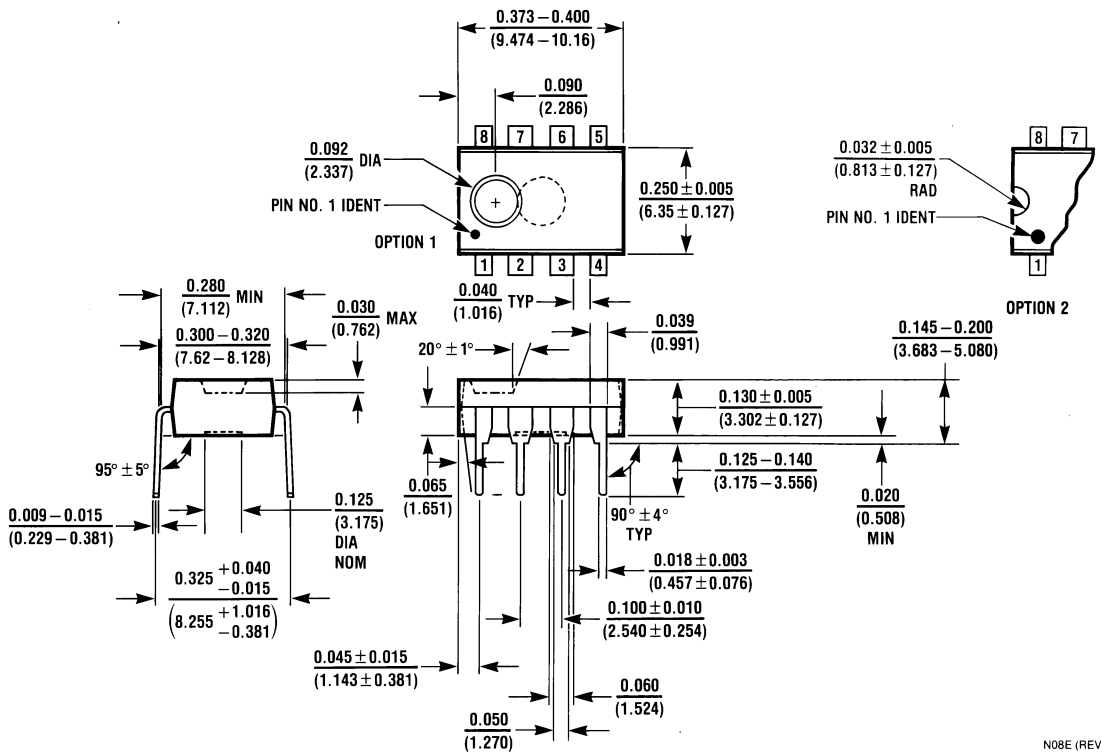
| Temperature Range | | Package | NSC Package Number |
|----------------------------------------------------------------------|---------------------------------------------------------------------|------------------------|--------------------------|
| Military $-55^{\circ}\text{C} \leq T_A \leq +125^{\circ}\text{C}$ | Commercial $0^{\circ}\text{C} \leq T_A \leq +70^{\circ}\text{C}$ | | |
| | LM4250CN | 8-Pin Molded DIP | N08E |
| | LM4250CM LM4250CMX | 8-Pin Surface Mount | M08A |
| LM4250J-MIL | | 8-Pin Ceramic DIP | J08E |
| | LM4250CH | 8-Pin Metal Can | H08C |

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



M08A (REV H)

Small Outline Package (M)
Order Number LM4250CM or LM4250CMX
NS Package Number M08A



N08E (REV F)

Molded Dual-In-Line Package (N)
Order Number LM4250CN
NS Package Number N08E